# **MOSFET** - Power, Single P-Channel, Small Signal -20 V, -127 mA

### NTNS2K1P021Z

#### **Features**

- Low Profile Ultra Small Package, XDFN3 (0.62 x 0.42 x 0.4 mm) for Extremely Space–Constrained Applications
- -1.5 V Gate Drive
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### **Applications**

- Small Signal Load Switch
- High Speed Interfacing
- Level Shift

#### MAXIMUM RATINGS (T<sub>J</sub> = 25°C unless otherwise stated)

Parameter			Symbol	Value	Unit			
Drain-to-Source Voltage			V <sub>DSS</sub>	20	V			
Gate-to-Source Volta	age		V <sub>GS</sub>	±8	V			
Continuous Drain	Steady	T <sub>A</sub> = 25°C	ID	-127	mΑ			
Current (Note 1)	State	T <sub>A</sub> = 85°C		-91	~			
	t ≤ 5 s	T <sub>A</sub> = 25°C		-146	O			
Power Dissipation (Note 1)	Steady State	$T_A = 25^{\circ}C$	Pb	125	mW			
	t ≤ 5 s	.GN	CF.	166	3			
Pulsed Drain Current	t <sub>p</sub> = 10 μs		I <sub>DM</sub>	-488	mA			
Operating Junction and Storage Temperature Range			TJ, T <sub>STG</sub>	–55 to 150	°C			
Source Current (Body Diode) (Note 2)			Is	200	mA			
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)						TL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- Surface-mounted on FR4 board using the minimum recommended pad size, or 2 mm<sup>2</sup>, 1 oz Cu.
- 2. Pulse Test: pulse width ≤ 300 μs, duty cycle ≤ 2%

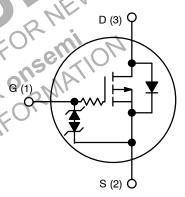


#### ON Semiconductor®

#### www.onsemi.com

V <sub>(BR)DSS</sub>	R <sub>DS(on)</sub> MAX	I <sub>D</sub> Max
	5.0 Ω @ -4.5 V	
–20 V	7.0 Ω @ -1.8 V	-127 mA
	20 Ω @ -1.2 V	GIZ

#### P-CHANNEL MOSFET



#### **MARKING DIAGRAM**





XDFN3 CASE 711BH

= Specific Device Code

M = Date Code

#### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
NTNS2K1P021ZTCG	XDFN3 (Pb-Free)	8000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

#### NTNS2K1P021Z

#### THERMAL RESISTANCE RATINGS

Parameter	Symbol	Max	Unit
Junction-to-Ambient - Steady State (Note 3)	$R_{\theta JA}$	998	°C/W
Junction-to-Ambient - t ≤ 5 s (Note 3)	$R_{\theta JA}$	751	C/VV

<sup>3.</sup> Surface–mounted on FR4 board using the minimum recommended pad size, or 2 mm<sup>2</sup>, 1 oz Cu.

## **ELECTRICAL CHARACTERISTICS** ( $T_J = 25^{\circ}C$ unless otherwise stated)

Parameter	Symbol	Test Condition	1	Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0 \text{ V}, I_D = -25$	0 μΑ	-20			V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{GS} = 0 \text{ V}, V_{DS} = -5 \text{ V}$	T <sub>J</sub> = 25°C			-50	nA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{GS} = 0 \text{ V}, V_{DS} = -16 \text{ V}$	T <sub>J</sub> = 25°C			-100	nA
Gate-to-Source Leakage Current	I <sub>GSS</sub>	V <sub>DS</sub> = 0 V, V <sub>GS</sub> = ±	±5 V			±100	nA
ON CHARACTERISTICS (Note 4)						~IGI	
Gate Threshold Voltage	V <sub>GS(TH)</sub>	$V_{GS} = V_{DS}, I_D = -25$	50 μΑ	-0.4		<b>9</b> –1.0	V
		$V_{GS} = -4.5 \text{ V}, I_D = -1$	00 mA		2.1	5.0	
Drain-to-Source On Resistance	R <sub>DS(on)</sub>	$V_{GS} = -1.8 \text{ V}, I_D = -2.8 \text{ V}$	20 mA	NE	3.6	7.0	Ω
		$V_{GS} = -1.2 \text{ V, I}_D = -10 \text{ mA}$		2 1	7.3	20	
Forward Transconductance	9 <sub>FS</sub>	$V_{DS} = -5 \text{ V}, I_D = -125 \text{ mA}$		SILL)	0.35		S
Source-Drain Diode Voltage	$V_{SD}$	$V_{GS} = 0 \text{ V}, I_{S} = -10$	) mA	50,7	-0.6	-1.0	V
CHARGES & CAPACITANCES							
Input Capacitance	C <sub>ISS</sub>	WE, C	70,50		12.8		
Output Capacitance	Coss	V <sub>GS</sub> = 0 V, freq = 1 MHz, V <sub>DS</sub> = -15 V 2.8			pF		
Reverse Transfer Capacitance	C <sub>RSS</sub>			2.0			
SWITCHING CHARACTERISTICS, VGS = 4.5 V (Note 4)							
Turn-On Delay Time	t <sub>d(ON)</sub>	CO, 1/1/2			37		
Rise Time	trck	$V_{GS} = -4.5 \text{ V, } V_{DD} = I_D = 200 \text{ mA, } R_G = 10.00 \text{ mA}$	–15 V,		71		
Turn-Off Delay Time	t <sub>d</sub> (OFF)	$\tilde{I}_D = 200 \text{ mA}, R_G =$	2 Ω		280		ns
Fall Time	45				171		

<sup>4.</sup> Switching characteristics are independent of operating junction temperatures.

#### NTNS2K1P021Z

#### **TYPICAL CHARACTERISTICS**

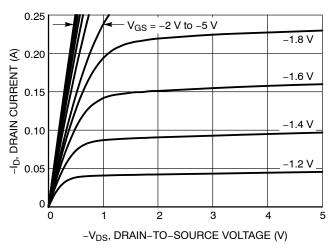
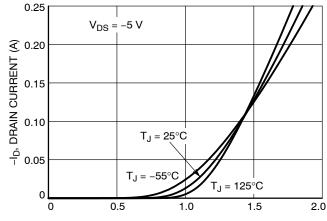


Figure 1. On-Region Characteristics



-V<sub>GS</sub>, GATE-TO-SOURCE VOLTAGE (V) Figure 2. Transfer Characteristics

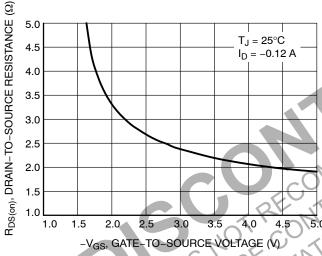
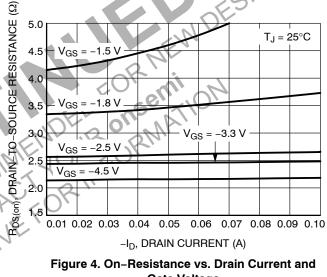


Figure 3. On-Resistance vs. Gate-to-Source Voltage



**Gate Voltage** 

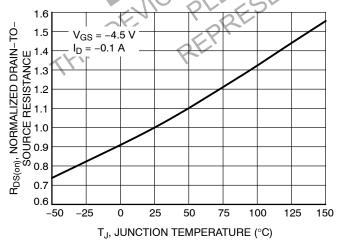


Figure 5. On-Resistance Variation with **Temperature** 

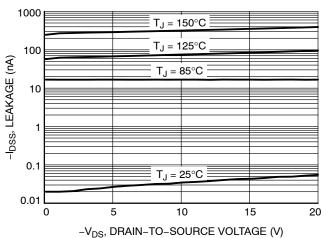


Figure 6. Drain-to-Source Leakage Current vs. Voltage

#### NTNS2K1P021Z

#### **TYPICAL CHARACTERISTICS**

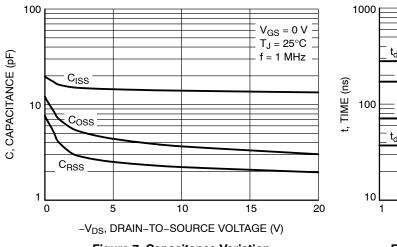


Figure 7. Capacitance Variation

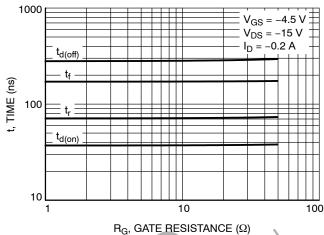


Figure 8. Resistive Switching Time Variation

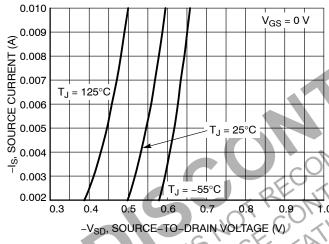


Figure 9. Diode Forward Voltage vs. Current

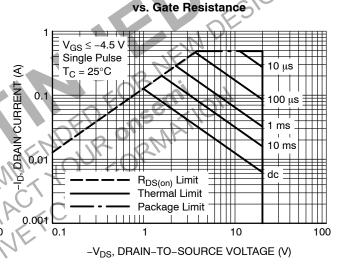


Figure 10. Maximum Rated Forward Biased Safe Operating Area

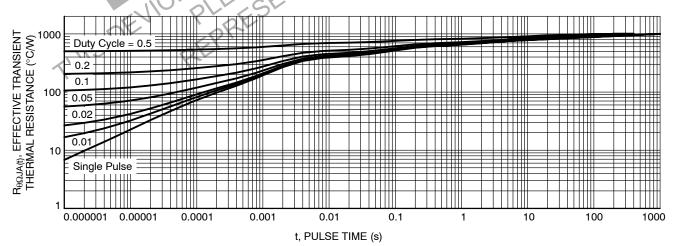


Figure 11. Thermal Response





PIN 1 REFERENCE

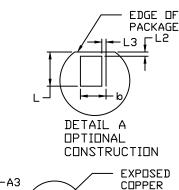
## **XDFN3 0.42x0.62, 0.3P** CASE 711BH

CASE 711BH ISSUE A

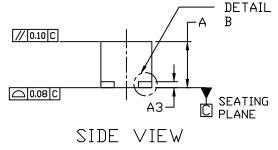
**DATE 29 APR 2018** 

#### NOTES:

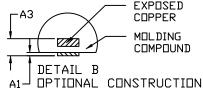
- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- DIMENSION 6 AND 61 APPLIES TO THE PLATED TERMINALS AND IS MEASURED BETWEEN 0.20 AND 0.25 FROM THE TERMINAL TIP.
- 4. COPLANARITY APPLIES TO THE PLATED TERMINALS.

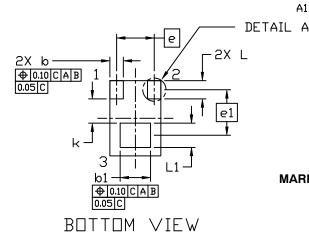


	MILLIMETERS		
DIM	MIN.	N□M.	MAX.
Α	0.33	0.38	0.43
A1			0.07
A3	(	.13 REF	
b	0.05	0.11	0.17
b1	0.20	0.25	0.30
D	0.32	0.42	0.52
Ε	0.52	0.62	0.72
e	0.30 BSC		
e1	0.38 BSC		
L	0.09	0.15	0.21
L1	0.15	0.20	0.25
L2			0.03
L3			0.03
k	0.20 REF		



TOP VIEW





# GENERIC MARKING DIAGRAM\*



X = Specific Device CodeM = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G", may or not be present. Some products may not follow the Generic Marking.

PACKAGE DUTLINE	<u> </u>	<b>⊢</b> 0.35
0.29 0.11 2X 0.21 0.52		0.30 2X 0.25 0.31 PITCH
		DE D

RECOMMENDED MOUNTING FOOTPRINT

		marking. Pb–Free indicator, "G", may or not be present. Some products may not follow the Generic Marking.
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